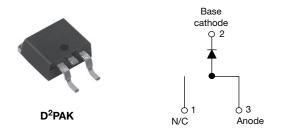


# VS-12TQ035SPbF, VS-12TQ040SPbF, VS-12TQ045SPbF

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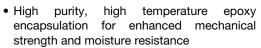
# **High Performance Schottky Rectifier, 15 A**



PRODUCT SUMMARY					
Package	D <sup>2</sup> PAK				
I <sub>F(AV)</sub>	15 A				
$V_{R}$	35 V, 40 V, 45 V				
V <sub>F</sub> at I <sub>F</sub>	0.50 V				
I <sub>RM</sub>	70 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
Diode variation	Single die				
E <sub>AS</sub>	16 mJ				

### **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Very low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### **DESCRIPTION**

The VS-12TQ...SPbF Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	15	Α			
V <sub>RRM</sub>	Range	35 to 45	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	990	А			
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.50	V			
T <sub>J</sub>	Range	-55 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-12TQ035SPbF	VS-12TQ040SPbF	VS-12TQ045SPbF	UNITS	
Maximum DC reverse voltage	$V_{R}$	35	40	45	V	
Maximum working peak reverse voltage	$V_{RWM}$	33	40	40	V	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS	
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 120 °C	15	А		
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	990	А	
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse		250		
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2.4 A, L = 5.5 mH		16	mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to ze Frequency limited by T <sub>J</sub> maxim		2.4	А	

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# VS-12TQ035SPbF, VS-12TQ040SPbF, VS-12TQ045SPbF

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		15 A	- T <sub>.1</sub> = 25 °C	0.56	V
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	30 A	11 = 25 0	0.71	
See fig. 1	V FM (*)	15 A	T <sub>.1</sub> = 125 °C	0.50	
		30 A	- IJ = 125 C	0.64	
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm R}$ = Rated $V_{\rm R}$	1.75	- mA
See fig. 2		T <sub>J</sub> = 125 °C	V <sub>R</sub> = nateu V <sub>R</sub>	70	
Maximum junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		900	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5	8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

### Note

 $<sup>^{(1)}\,</sup>$  Pulse width  $<300~\mu s,$  duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C	
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation See fig. 4	2.0	°C/W	
Typical thermal resistant case to heatsink	ce,	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	C/VV	
Annyayimata waight				2	g	
Approximate weight				0.07	OZ.	
Marinting toward	minimum			6 (5)	kgf · cm	
Mounting torque -	maximum			12 (10)	(lbf · in)	
Marking device			Case style D <sup>2</sup> PAK	12TQ	045S	

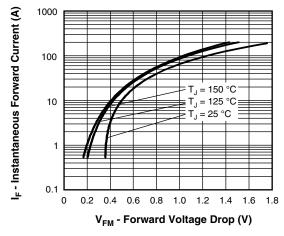


Fig. 1 - Maximum Forward Voltage Drop Characteristics

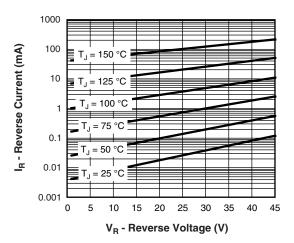


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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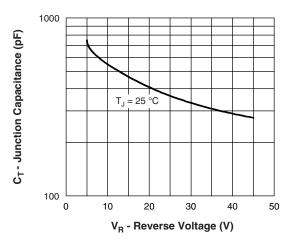


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

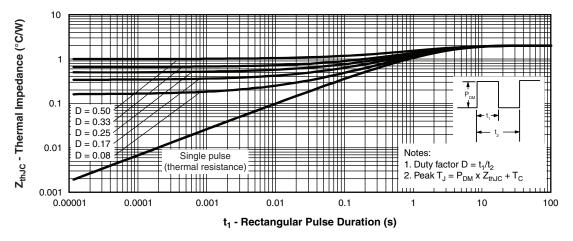


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

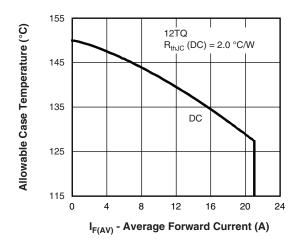


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

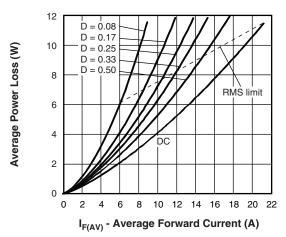
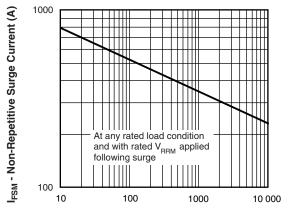


Fig. 6 - Forward Power Loss Characteristics

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t<sub>p</sub> - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

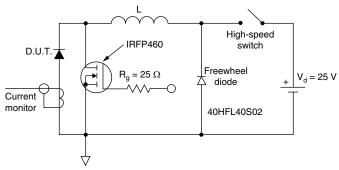
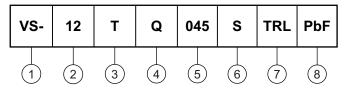


Fig. 8 - Unclamped Inductive Test Circuit

### **ORDERING INFORMATION TABLE**

Device code



- 1 Vishay Semiconductors product
- 2 Current rating
- 3 Package: T = TO-220
- 4 Schottky "Q" series 035 = 35 V
- 7 • None = tube (50 pieces)
  - TRL = tape and reel (left oriented)
  - TRR = tape and reel (right oriented)
- PbF = lead (Pb)-free

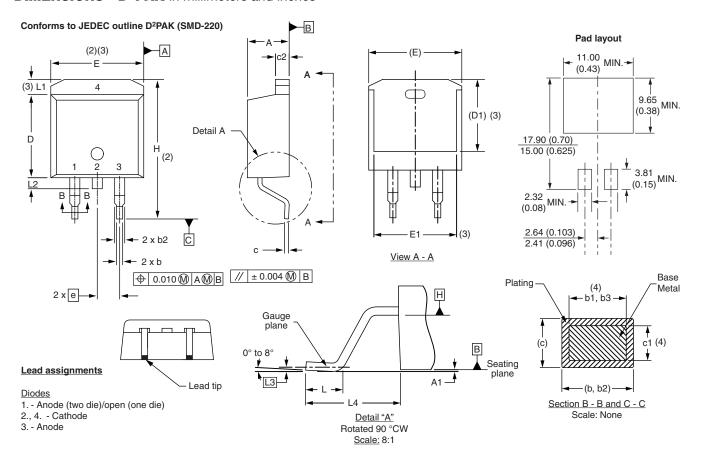
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95014</u>					
Part marking information	www.vishay.com/doc?95008				
Packaging information	www.vishay.com/doc?95032				

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# Vishay Semiconductors

# **D<sup>2</sup>PAK, TO-262**

### **DIMENSIONS - D<sup>2</sup>PAK** in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$  Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

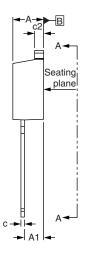
Document Number: 95014 Revision: 31-Mar-09

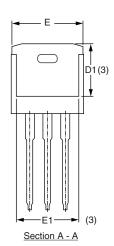
# D<sup>2</sup>PAK, TO-262



### **DIMENSIONS - TO-262** in millimeters and inches

# Modified JEDEC outline TO-262 (Datum A)—(2) (3) (3) 1 D D L2 B B B L (2) A L (2)





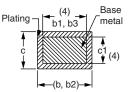
**♦**0.010**⋒**|A**⋒**|B

### Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

CVMPOL	MILLIMETERS		INC	INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100	BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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